

# **NCE N-Channel Super Trench Power MOSFET**

## **Description**

The NCEP4090GU uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS}(\text{ON})}$  and  $Q_{\text{g}}.$  This device is ideal for high-frequency switching and synchronous rectification.

# **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

#### **General Features**

- V<sub>DS</sub> =40V,I<sub>D</sub> =90A  $R_{DS(ON)}$ =2.2m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =3.3m $\Omega$  (typical) @  $V_{GS}$ =4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

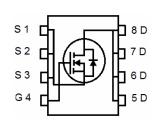
100% UIS TESTED! 100% ΔVds TESTED!

#### **DFN 5X6**









**Schematic Diagram** 

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP4090GU	NCEP4090GU	DFN5x6-8L	-	-	-

# Absolute Maximum Ratings (T<sub>c</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	90	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	63.6	А
Pulsed Drain Current	I <sub>DM</sub>	360	А
Maximum Power Dissipation	P <sub>D</sub>	70	W
Derating factor		0.56	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	500	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	1.8	°C/W

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# Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

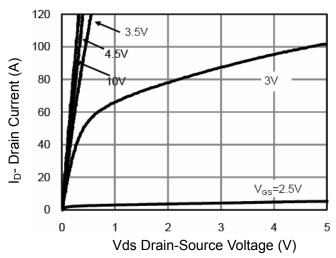
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	40		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	•					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.5	2.0	V
•	_	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	2.2	2.5	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	3.3	3.8	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	1	60	-	S
Dynamic Characteristics (Note4)	•		1			
Input Capacitance	C <sub>lss</sub>	V 90VVV 9V	-	2100	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V F=1.0MHz	-	773	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIHZ	-	15.5	-	PF
Switching Characteristics (Note 4)	•	15				
Turn-on Delay Time	t <sub>d(on)</sub>		-	7.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =20V,I <sub>D</sub> =20A	-	4.0	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{DD}$ =20V, $I_{D}$ =20A $V_{GS}$ =10V, $R_{G}$ =1.6 $\Omega$	-	37	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7.5	-	nS
Total Gate Charge	Qg	V 00V/1 00A	-	34.8	-	nC
Gate-Source Charge	Qgs	Q <sub>gs</sub> V <sub>DS</sub> =20V,I <sub>D</sub> =20A,		6.2		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	5.1		nC
Drain-Source Diode Characteristics	12.				1	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current (Note 2)			-	-	90	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	14	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	21	-	nC

#### Notes:

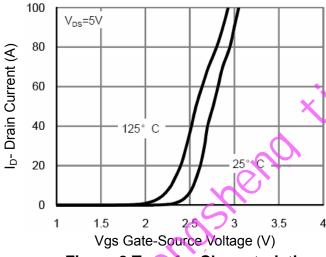
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=20V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$



# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

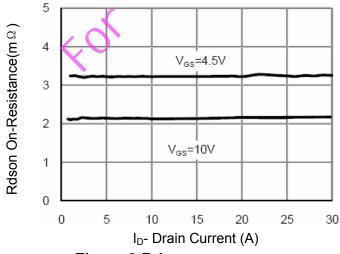


Figure 3 Rdson- Drain Current

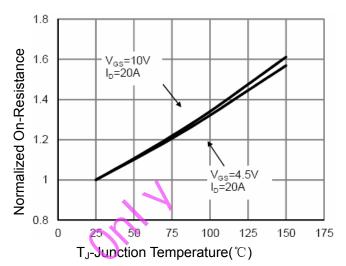


Figure 4 Rdson-Junction Temperature

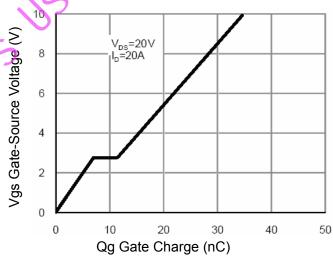


Figure 5 Gate Charge

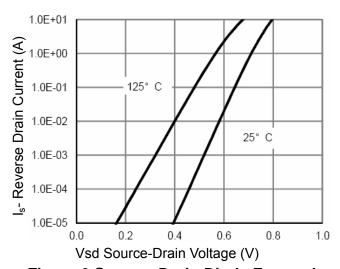


Figure 6 Source- Drain Diode Forward



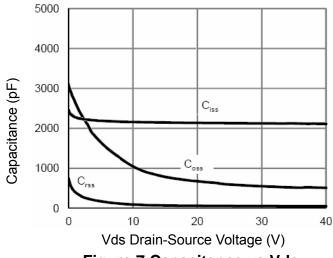


Figure 7 Capacitance vs Vds

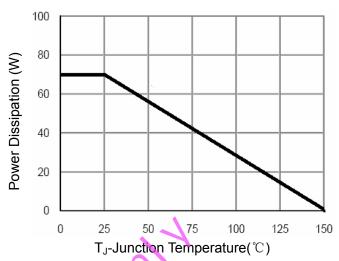


Figure 9 Power De-rating

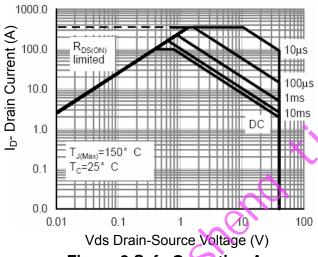


Figure 8 Safe Operation Area

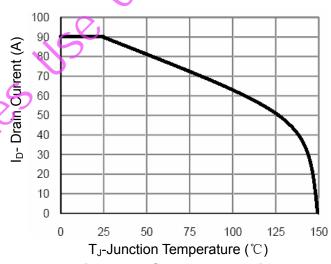


Figure 10 Current De-rating

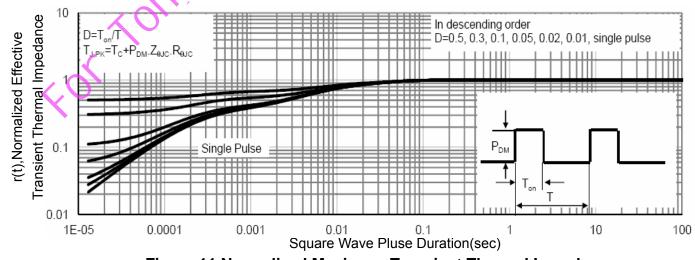
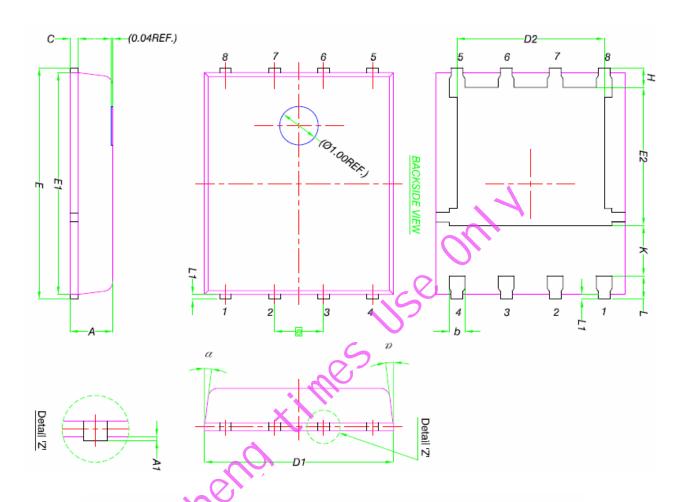


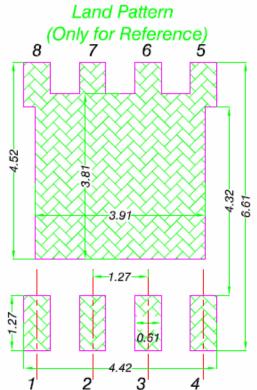
Figure 11 Normalized Maximum Transient Thermal Impedance



# **DFN5X6-8L Package Information**



	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
A	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е	1.27 BSC				
Н	0.41	0.51	0.61		
K	1.10	-	-		
L	0.51	0.61	0.71		
L1	0.06	0.13	0.20		
α	0°	-	12°		



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# NCEP4090GU

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